



BUK663R5-30C

N-channel TrenchMOS intermediate level FET

Rev. 02 — 16 November 2010

Product data sheet

1. Product profile

1.1 General description

Intermediate level gate drive N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using advanced TrenchMOS technology. This product has been designed and qualified to the appropriate AEC Q101 standard for use in high performance automotive applications.

1.2 Features and benefits

- AEC Q101 compliant
- Suitable for standard and logic level gate drive sources
- Suitable for thermally demanding environments due to 175 °C rating

1.3 Applications

- 12 V Automotive systems
- Electric and electro-hydraulic power steering
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}$; $T_j \leq 175^\circ\text{C}$	-	-	30	V
I_D	drain current	$V_{GS} = 10\text{ V}$; $T_{mb} = 25^\circ\text{C}$; see Figure 1	[1]	-	100	A
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; see Figure 2	-	-	158	W
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10\text{ V}$; $I_D = 25\text{ A}$; $T_j = 25^\circ\text{C}$; see Figure 11	-	2.9	3.5	$\text{m}\Omega$

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Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 100 \text{ A}$; $V_{sup} \leq 30 \text{ V}$; $R_{GS} = 50 \Omega$; $V_{GS} = 10 \text{ V}$; $T_{j(init)} = 25 \text{ }^\circ\text{C}$; unclamped	-	-	242	mJ
Dynamic characteristics						
Q_{GD}	gate-drain charge	$I_D = 25 \text{ A}$; $V_{DS} = 24 \text{ V}$; $V_{GS} = 10 \text{ V}$; see Figure 13 ; see Figure 14	-	20	-	nC

[1] Continuous current is limited by package.

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	Drain		
3	S	source		
mb	D	mounting base; connected to drain		

SOT404 (D2PAK)

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BUK663R5-30C	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}; T_j \leq 175^\circ\text{C}$	-	30	V	
V_{GS}	gate-source voltage	DC	[1]	-16	V	
		Pulsed		-20	V	
I_D	drain current	$T_{mb} = 25^\circ\text{C}; V_{GS} = 10\text{ V}$; see Figure 1	[3]	-	100	A
		$T_{mb} = 100^\circ\text{C}; V_{GS} = 10\text{ V}$; see Figure 1		-	100	A
I_{DM}	peak drain current	$T_{mb} = 25^\circ\text{C}; t_p \leq 10\text{ }\mu\text{s}$; pulsed; see Figure 3	-	616	A	
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; see Figure 2	-	158	W	
T_{stg}	storage temperature		-55	175	°C	
T_j	junction temperature		-55	175	°C	
Source-drain diode						
I_S	source current	$T_{mb} = 25^\circ\text{C}$	[3]	-	100	A
I_{SM}	peak source current	$t_p \leq 10\text{ }\mu\text{s}$; pulsed; $T_{mb} = 25^\circ\text{C}$		-	616	A
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 100\text{ A}; V_{sup} \leq 30\text{ V}; R_{GS} = 50\text{ }\Omega; V_{GS} = 10\text{ V}; T_{j(init)} = 25^\circ\text{C}$; unclamped	-	242	mJ	
$E_{DS(AL)R}$	repetitive drain-source avalanche energy		[4][5][6]	-	-	J

[1] -16V accumulated duration not to exceed 168 hrs.

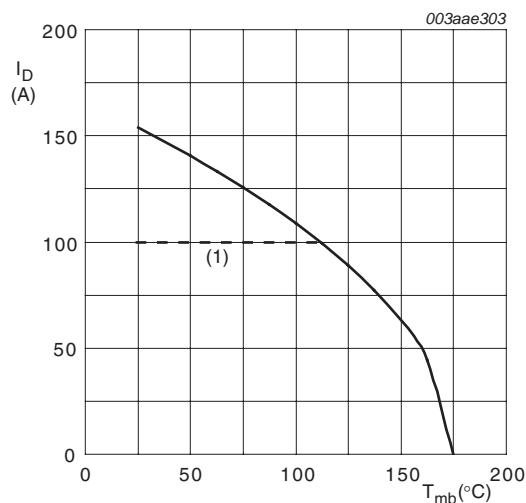
[2] Accumulated pulse duration not to exceed 5mins.

[3] Continuous current is limited by package.

[4] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

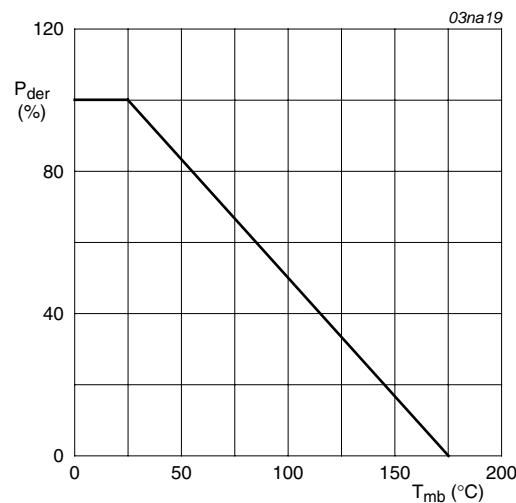
[5] Repetitive avalanche rating limited by an average junction temperature of 170 °C.

[6] Refer to application note AN10273 for further information.



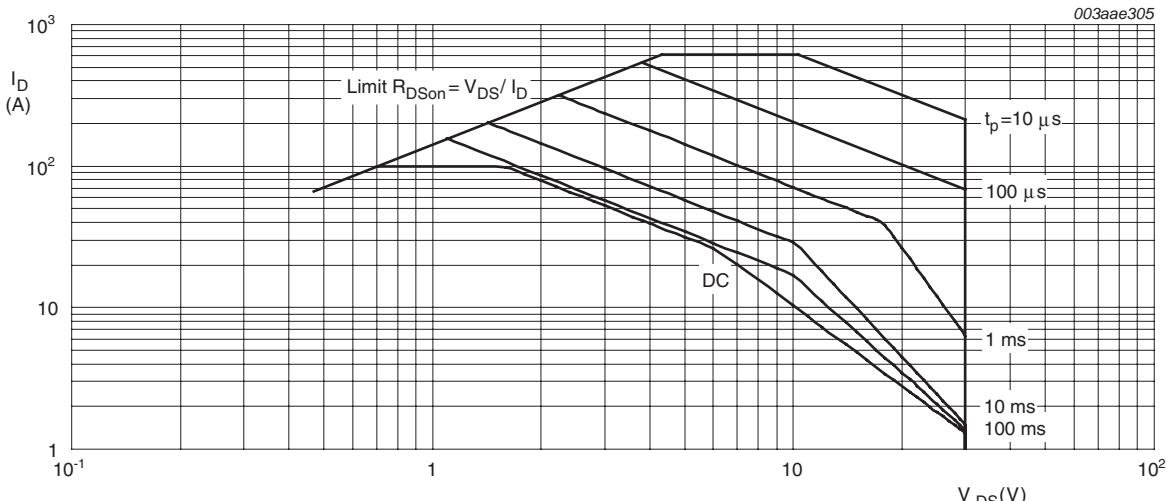
$V_{GS} \geq 10\text{ V}$
(1) Capped at 100 A due to package.

Fig 1. Continuous drain current as a function of mounting base temperature



$$P_{der} = \frac{P_{tot}}{P_{tot}(25^\circ\text{C})} \times 100\%$$

Fig 2. Normalized total power dissipation as a function of mounting base temperature



$T_{mb} = 25^\circ\text{C}$; I_{DM} is a single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j\text{-mb})}$	thermal resistance from junction to mounting base	see Figure 4	-	-	0.95	K/W

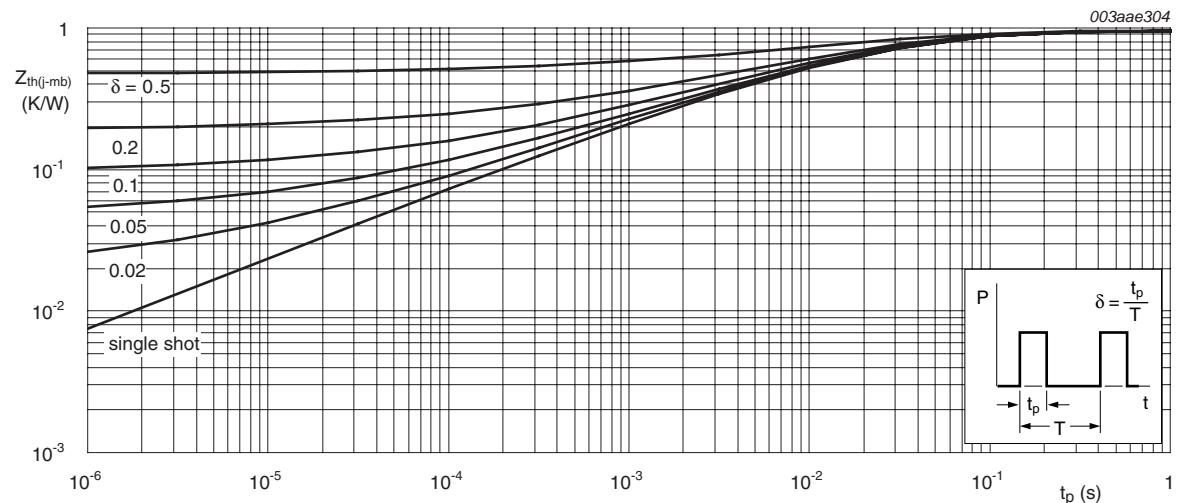


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

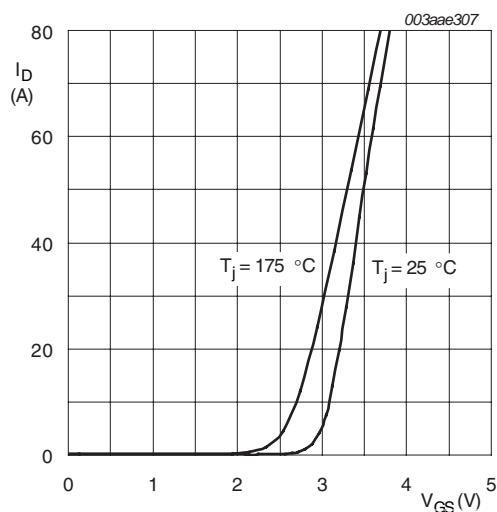
6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$ $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55^\circ C$	30	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25^\circ C$; see Figure 9 ; see Figure 10 $I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55^\circ C$; see Figure 9 $I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175^\circ C$; see Figure 9	1.8	2.3	2.8	V
I_{DSS}	drain leakage current	$V_{DS} = 30 V; V_{GS} = 0 V; T_j = 175^\circ C$ $V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25^\circ C$	-	-	500	μA
I_{GSS}	gate leakage current	$V_{DS} = 0 V; V_{GS} = 20 V; T_j = 25^\circ C$ $V_{DS} = 0 V; V_{GS} = -20 V; T_j = 25^\circ C$	-	2	100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 V; I_D = 25 A; T_j = 25^\circ C$; see Figure 11 $V_{GS} = 5 V; I_D = 25 A; T_j = 25^\circ C$; see Figure 11 $V_{GS} = 4.5 V; I_D = 25 A; T_j = 25^\circ C$; see Figure 11 $V_{GS} = 10 V; I_D = 25 A; T_j = 175^\circ C$; see Figure 12 ; see Figure 11	-	2.9	3.5	$m\Omega$
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	$I_D = 25 A; V_{DS} = 24 V; V_{GS} = 10 V$; see Figure 13 ; see Figure 14 $I_D = 25 A; V_{DS} = 24 V; V_{GS} = 5 V$; see Figure 13 ; see Figure 14	-	78	-	nC
Q_{GS}	gate-source charge	$I_D = 25 A; V_{DS} = 24 V; V_{GS} = 10 V$	-	15	-	nC
Q_{GD}	gate-drain charge	see Figure 13 ; see Figure 14	-	20	-	nC
C_{iss}	input capacitance	$V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz; T_j = 25^\circ C$; see Figure 15	-	3530	4707	pF
C_{oss}	output capacitance	$V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz; T_j = 25^\circ C$; see Figure 14	-	623	748	pF
C_{rss}	reverse transfer capacitance	$V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz; T_j = 25^\circ C$	-	381	522	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 25 V; R_L = 1 \Omega; V_{GS} = 10 V$	-	19	-	ns
t_r	rise time	$R_{G(ext)} = 10 \Omega$	-	54	-	ns
$t_{d(off)}$	turn-off delay time		-	135	-	ns
t_f	fall time		-	83	-	ns
L_D	internal drain inductance	from upper edge of drain mounting base to centre of die ; $T_j = 25^\circ C$	-	3.5	-	nH
L_S	internal source inductance	from source lead to source bond pad ; $T_j = 25^\circ C$	-	7.5	-	nH

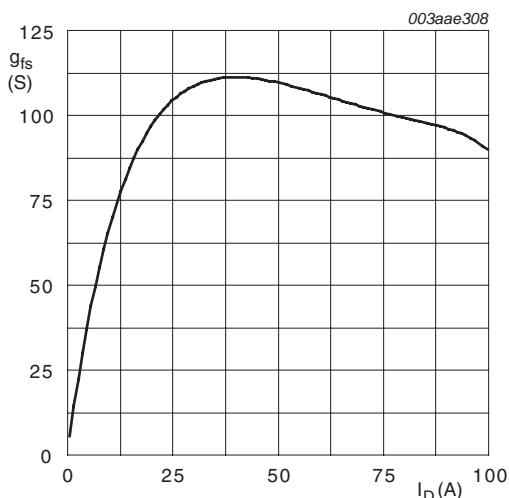
Table 6. Characteristics ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Source-drain diode						
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$; see Figure 16	-	0.8	1.2	V
t_{rr}	reverse recovery time	$I_S = 20 \text{ A}; dI_S/dt = -100 \text{ A}/\mu\text{s}; V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}$	-	46	-	ns
Q_r	recovered charge		-	57	-	nC



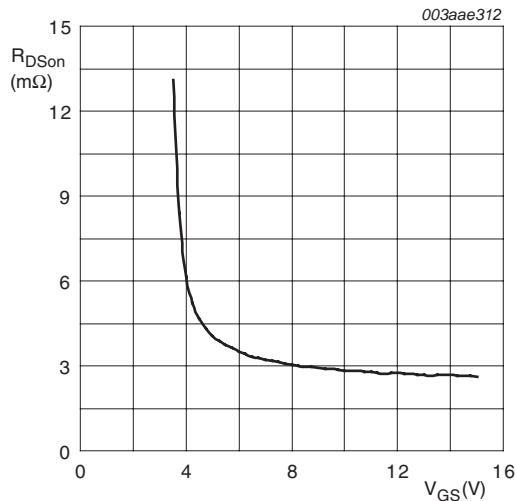
$$V_{DS} > I_D \times R_{DSon}$$

Fig 5. Transfer characteristics: drain current as a function of gate-source voltage; typical values



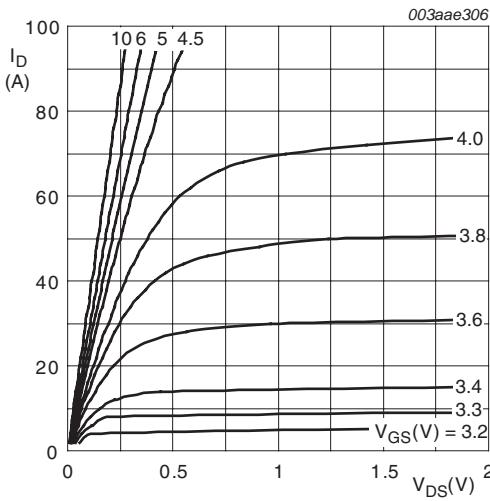
$$T_j = 25 \text{ }^\circ\text{C}; V_{DS} = 25 \text{ V}$$

Fig 6. Forward transconductance as a function of drain current; typical values



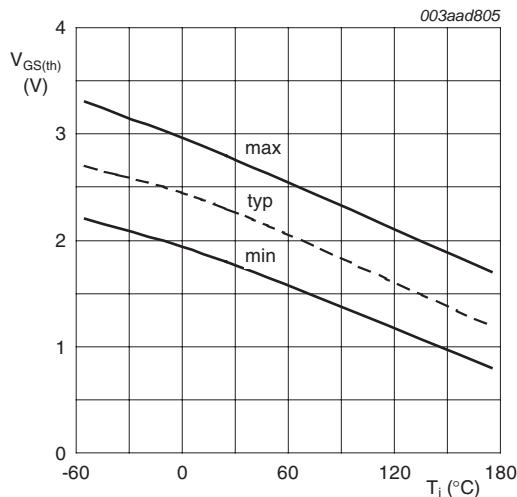
$$T_j = 25 \text{ }^\circ\text{C}; I_D = 25 \text{ A}$$

Fig 7. Drain-source on-state resistance as a function of gate-source voltage; typical values.



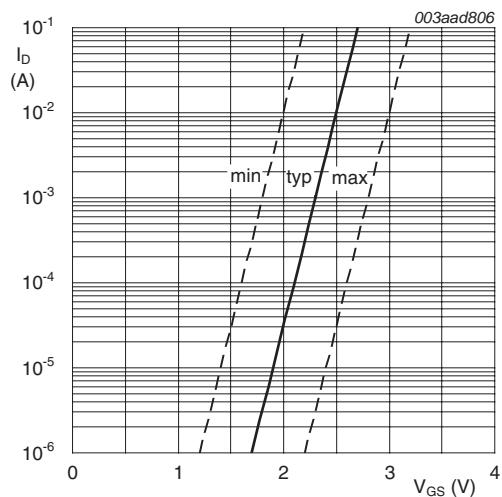
$$T_j = 25 \text{ }^\circ\text{C}$$

Fig 8. Output characteristics: drain current as a function of drain-source voltage; typical values



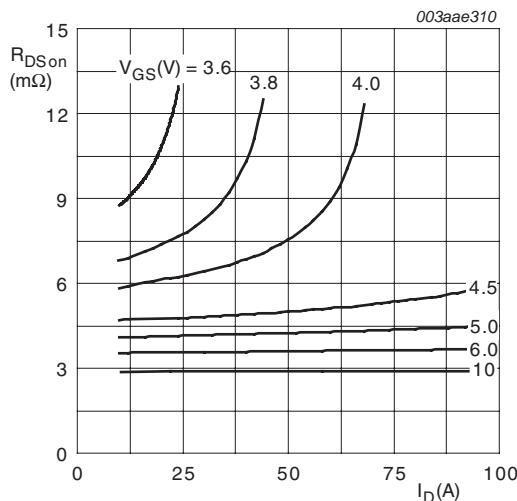
$I_D = 1\text{mA}; V_{DS} = V_{GS}$

Fig 9. Gate-source threshold voltage as a function of junction temperature



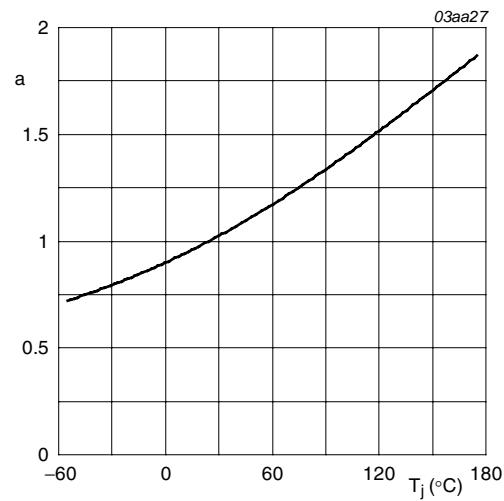
$T_j = 25\text{ }^{\circ}\text{C}; V_{DS} = 5\text{V}$

Fig 10. Sub-threshold drain current as a function of gate-source voltage



$T_j = 25\text{ }^{\circ}\text{C}$

Fig 11. Drain-source on-state resistance as a function of drain current; typical values



$$a = \frac{R_{DS(on)}}{R_{DS(on)(25^{\circ}\text{C})}}$$

Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature

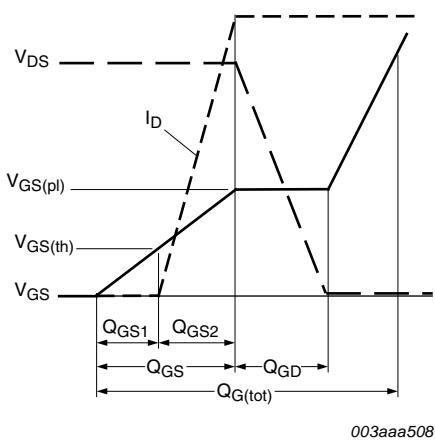


Fig 13. Gate charge waveform definitions

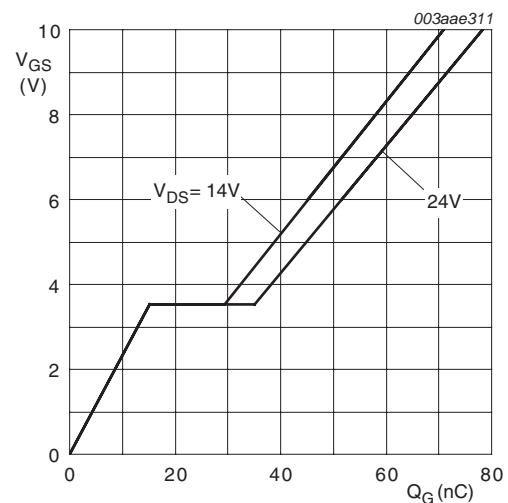
 $T_j = 25^\circ C; I_D = 25A$

Fig 14. Gate-source voltage as a function of gate charge; typical values

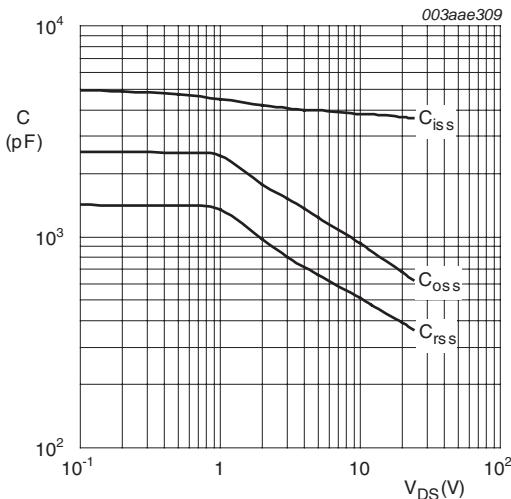
 $V_{GS} = 0V; f = 1MHz$

Fig 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

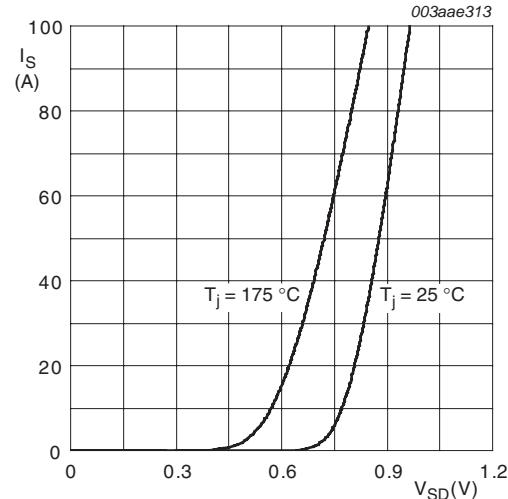
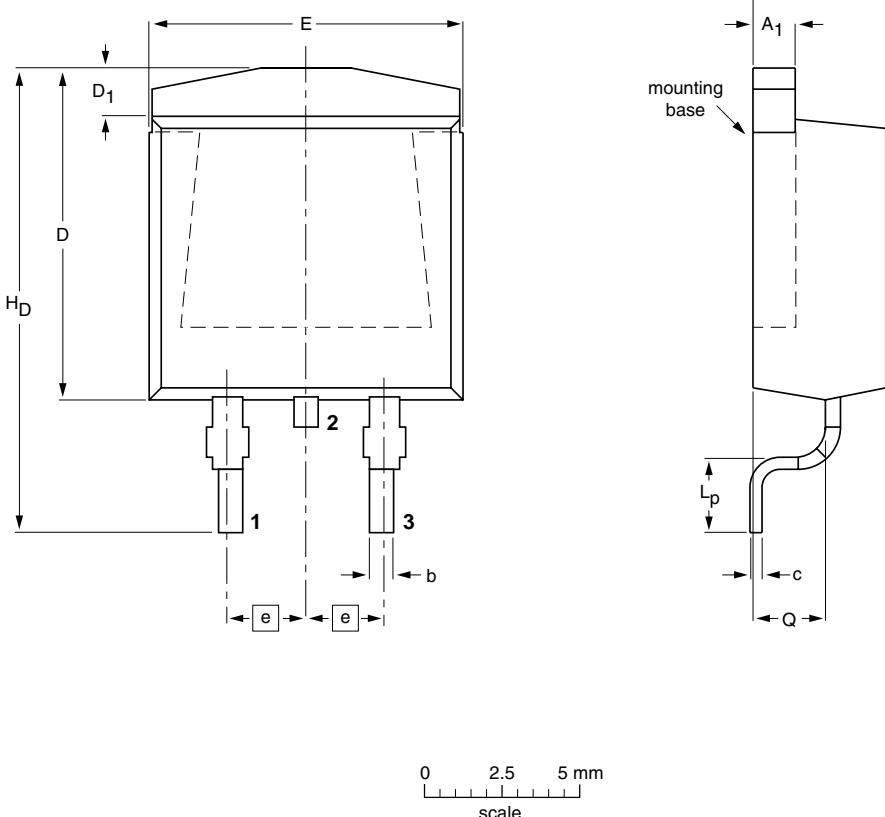
 $V_{GS} = 0V$

Fig 16. Source current as a function of source-drain voltage; typical values

7. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)

SOT404



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	c	D _{max.}	D ₁	E	e	L _p	H _D	Q
mm	4.50 4.10	1.40 1.27	0.85 0.60	0.64 0.46	11	1.60 1.20	10.30 9.70	2.54	2.90 2.10	15.80 14.80	2.60 2.20

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT404						05-02-11 06-03-16

Fig 17. Package outline SOT404 (D2PAK)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BUK663R5-30C v.2	20101116	Product data sheet	-	BUK663R5-30C v.1
Modifications:		<ul style="list-style-type: none">• Status changed from objective to product.• Various changes to content.		
BUK663R5-30C v.1	20100521	Objective data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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JONHON

«JONHON» (основан в 1970 г.)

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«FORSTAR» (основан в 1998 г.)

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